# NSN 5961-00-891-7176

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#### Inclosure Material:

Metal

**Overall Length:** 

0.406 inches

# Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Threaded stud

**Overall Width Across Flats:** 

0.875 inches

Thread Size:

# 0.312 inches

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown

voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 5.00 amperes source cutoff current and 20.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

100.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

#### **Special Features:**

Junction pattern arrangement: npn

#### Thread Series Designator:

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug

#### **Specification Data:**

80131-release4826 professional/industrial association specification

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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